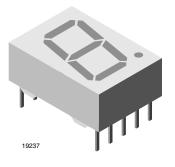


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## **Vishay Semiconductors**

## Standard 7-Segment Display 13 mm



### DESCRIPTION

The TDS.51.. series are 13 mm character seven segment LED displays in a very compact package.

The displays are designed for a viewing distance up to 7 m and available in four bright colors. The grey package surface and the evenly lighted untinted segments provide an optimum on-off contrast.

All displays are categorized in luminous intensity groups. That allows users to assemble displays with uniform appearence. Typical applications include instruments, panel meters, point-of-sale terminals and household equipment.

#### **FEATURES**

- Evenly lighted segments
- · Grey package surface
- Untinted segments
- · Luminous intensity categorized
- Yellow and green categorized for color
- · Wide viewing angle
- · Suitable for DC and high peak current
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- Panel meters
- Test- and measure-equipment
- Point-of-sale terminals
- Control units
- TV sets

#### **PRODUCT GROUP AND PACKAGE DATA**

- Product group: Display
- · Package: 13 mm
- Product series: Standard
- Angle of half intensity: ± 50°

| PARTS TAB   | PARTS TABLE |                             |      |                        |      |               |                   |      |                        |      |       |                   |           |                |
|-------------|-------------|-----------------------------|------|------------------------|------|---------------|-------------------|------|------------------------|------|-------|-------------------|-----------|----------------|
| PART        | COLOR       | LUMINOUS INTENSITY<br>(µcd) |      | at I <sub>F</sub> (nm) |      | /ELEN<br>(nm) | at I <sub>F</sub> |      | FORWARD VOLTAGE<br>(V) |      | LTAGE | at I <sub>F</sub> | CIRCUITRY |                |
|             |             | MIN.                        | TYP. | MAX.                   | (mA) | MIN.          | TYP.              | MAX. | (mA)                   | MIN. | TYP.  | MAX.              | (mA)      |                |
| TDSO5150    | Orange red  | 700                         | 5000 | -                      | 10   | 612           | -                 | 625  | 10                     | -    | 2     | 3                 | 20        | Common anode   |
| TDSO5150-LM | Orange red  | 2800                        | -    | 9000                   | 10   | 612           | -                 | 625  | 10                     | -    | 2     | 3                 | 20        | Common anode   |
| TDSO5150-M  | Orange red  | 4500                        | -    | 9000                   | 10   | 612           | -                 | 625  | 10                     | -    | 2     | 3                 | 20        | Common anode   |
| TDSO5160    | Orange red  | 700                         | 5000 | -                      | 10   | 612           | -                 | 625  | 10                     | -    | 2     | 3                 | 20        | Common cathode |
| TDSO5160-LM | Orange red  | 2800                        | -    | 9000                   | 10   | 612           | -                 | 625  | 10                     | -    | 2     | 3                 | 20        | Common cathode |
| TDSY5150    | Yellow      | 700                         | 4200 | -                      | 10   | 581           | -                 | 594  | 10                     | -    | 2.4   | 3                 | 20        | Common anode   |
| TDSY5160    | Yellow      | 700                         | 4200 | -                      | 10   | 581           | -                 | 594  | 10                     | -    | 2.4   | 3                 | 20        | Common cathode |
| TDSG5150    | Green       | 700                         | 9500 | -                      | 10   | 562           | -                 | 575  | 10                     | -    | 2.4   | 3                 | 20        | Common anode   |
| TDSG5150-MN | Green       | 4500                        | -    | 14 000                 | 10   | 562           | -                 | 575  | 10                     | -    | 2.4   | 3                 | 20        | Common anode   |
| TDSG5150-N  | Green       | 7000                        | -    | 14 000                 | 10   | 562           | -                 | 575  | 10                     | -    | 2.4   | 3                 | 20        | Common anode   |
| TDSG5160    | Green       | 700                         | 9500 | -                      | 10   | 562           | -                 | 575  | 10                     | -    | 2.4   | 3                 | 20        | Common cathode |
| TDSG5160-MN | Green       | 4500                        | -    | 14 000                 | 10   | 562           | -                 | 575  | 10                     | -    | 2.4   | 3                 | 20        | Common cathode |
| TDSG5160-N  | Green       | 7000                        | -    | 14 000                 | 10   | 562           | -                 | 575  | 10                     | -    | 2.4   | 3                 | 20        | Common cathode |



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| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)<br>TDSO5150, TDSO5160, TDSY5150, TDSY5160, TDSG5150, TDSG5160 |                                       |                   |            |      |  |  |  |  |
|---|---------------------------------------|-------------------|------------|------|--|--|--|--|
| PARAMETER   | TEST CONDITION                        | SYMBOL            | VALUE      | UNIT |  |  |  |  |
| Reverse voltage per segment or DP   |                                       | V <sub>R</sub>    | 6          | V    |  |  |  |  |
| DC forward current per segment or DP  |                                       | I <sub>F</sub>    | 25         | mA   |  |  |  |  |
| Surge forward current per segment or DP   | $t_p \le 10 \ \mu s$ (non repetitive) | I <sub>FSM</sub>  | 0.15       | A    |  |  |  |  |
| Power dissipation   | T <sub>amb</sub> ≤ 45 °C              | Pv                | 550        | mW   |  |  |  |  |
| Junction temperature  |                                       | Тj                | 100        | °C   |  |  |  |  |
| Operating temperature range   |                                       | T <sub>amb</sub>  | -40 to +85 | °C   |  |  |  |  |
| Storage temperature range   |                                       | T <sub>stg</sub>  | -40 to +85 | °C   |  |  |  |  |
| Soldering temperature   | $t \le 3$ s, 2 mm below seating plane | T <sub>sd</sub>   | 260        | °C   |  |  |  |  |
| Thermal resistance LED junction/ambient   |                                       | R <sub>thJA</sub> | 100        | K/W  |  |  |  |  |

# OPTICAL AND ELECTRICAL CHARACTERISTICS ( $T_{amb}$ = 25 °C, unless otherwise specified) TDS05150, TDS05150-LM, TDS05150-M, TDS05160, TDS05160-LM, ORANGE RED

| PARAMETER   | TEST CONDITION         | PART                                    | SYMBOL         | MIN. | TYP. | MAX. | UNIT |
|---|------------------------|---|----------------|------|------|------|------|
|   |                        | TDSO5150                                |                | 700  | 5000 | -    |      |
|   |                        | TDSO5150-LM                             | 2800           | -    | 9000 | μcd  |      |
| Luminous intensity per segment (digit average) <sup>(1)</sup> | I <sub>F</sub> = 10 mA | TDSO5150-M I <sub>V</sub>               |                | 4500 | -    |      | 9000 |
| (digit avoidgo)   |                        | TDSO5160                                |                | 700  | 5000 | -    |      |
|   |                        | TDSO5160-LM                             |                | 2800 | -    | 9000 |      |
| Dominant wavelength   | I <sub>F</sub> = 10 mA |   | $\lambda_d$    | 612  | -    | 625  | nm   |
| Peak wavelength<br>Angle of half intensity                    | I <sub>F</sub> = 10 mA | - TDSO5150,                             |                | -    | 630  | -    | nm   |
|   | I <sub>F</sub> = 10 mA | TDSO5150-M,<br>TDSO5160,<br>TDSO5160-LM | j              | -    | ± 50 | -    | deg  |
| Forward voltage per segment or DP                             | I <sub>F</sub> = 20 mA |   | V <sub>F</sub> | -    | 2    | 3    | V    |
| Reverse voltage per segment or DP                             | I <sub>R</sub> = 10 μA | TD000100 EM                             | V <sub>R</sub> | 6    | 15   | -    | V    |

#### Note

(1) I<sub>Vmin</sub> and I<sub>V</sub> groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is ≥ 0.5, excluding decimal points and colon.

## **OPTICAL AND ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, unless otherwise specified) **TDSY5150, TDSY5160, YELLOW**

| <u> </u>                          |                        |                       |                |      | -    |      |      |
|-----------------------------------|------------------------|-----------------------|----------------|------|------|------|------|
| PARAMETER                         | TEST CONDITION         | PART                  | SYMBOL         | MIN. | TYP. | MAX. | UNIT |
| Luminous intensity per segment    | l <sub>F</sub> = 10 mA | TDSY5150              |                | 700  | 4200 | -    | μcd  |
| (digit average) <sup>(1)</sup>    | $I_F = 10 IIIA$        | TDSY5160              |                | 700  | 4200 | -    |      |
| Dominant wavelength               | I <sub>F</sub> = 10 mA |                       | $\lambda_d$    | 581  | -    | 594  | nm   |
| Peak wavelength                   | I <sub>F</sub> = 10 mA |                       | λρ             | -    | 585  | -    | nm   |
| Angle of half intensity           | I <sub>F</sub> = 10 mA | TDSY5150,<br>TDSY5160 | j              | -    | ± 50 | -    | deg  |
| Forward voltage per segment or DP | I <sub>F</sub> = 20 mA | 12010100              | V <sub>F</sub> | -    | 2.4  | 3    | V    |
| Reverse voltage per segment or DP | I <sub>R</sub> = 10 μA |                       | V <sub>R</sub> | 6    | 15   | -    | V    |

#### Note

(1) I<sub>Vmin.</sub> and I<sub>V</sub> groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is ≥ 0.5, excluding decimal points and colon.

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| OPTICAL AND ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25$ °C, unless otherwise specified)<br>TDSG5150, TDSG5150-MN, TDSG5150-N, TDSG5160, TDSG5160-MN, TDSG5160-N, GREEN |                        |                          |                |      |      |        |      |  |  |  |
|--|------------------------|--------------------------|----------------|------|------|--------|------|--|--|--|
| PARAMETER  | TEST CONDITION         | PART                     | SYMBOL         | MIN. | TYP. | MAX.   | UNIT |  |  |  |
|  |                        | TDSG5150                 |                | 700  | 9500 | -      |      |  |  |  |
|  |                        | TDSG5150-MN              |                | 4500 | -    | 14 000 |      |  |  |  |
| Luminous intensity per segment   | 1. 10 m 4              | TDSG5150-N               |                | 7000 | -    | 14 000 |      |  |  |  |
| (digit average) (1)  | I <sub>F</sub> = 10 mA | TDSG5160                 |                | 700  | 9500 | -      | μcd  |  |  |  |
|  |                        | TDSG5160-MN              | -              | 4500 | -    | 14 000 |      |  |  |  |
|  |                        | TDSG5160-N               |                | 7000 | -    | 14 000 |      |  |  |  |
| Dominant wavelength  | I <sub>F</sub> = 10 mA | TDSG5150,                | $\lambda_d$    | 562  | -    | 575    | nm   |  |  |  |
| Peak wavelength  | I <sub>F</sub> = 10 mA | TDSG5150-MN,             | λρ             | -    | 565  | -      | nm   |  |  |  |
| Angle of half intensity  | I <sub>F</sub> = 10 mA | TDSG5150-N.<br>TDSG5160. | j              | -    | ± 50 | -      | deg  |  |  |  |
| Forward voltage per segment or DP  | I <sub>F</sub> = 20 mA | TDSG5160-MN,             | VF             | -    | 2.4  | 3      | V    |  |  |  |
| Reverse voltage per segment or DP  | I <sub>R</sub> = 10 μA | TDSG5160-N               | V <sub>R</sub> | 6    | 15   | -      | V    |  |  |  |

#### Note

(1)  $I_{Vmin.}$  and  $I_V$  groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is  $\ge$  0.5, excluding decimal points and colon.

| LUMINOUS INTENSITY CLASSIFICATION |                             |        |  |  |  |  |  |  |  |
|-----------------------------------|-----------------------------|--------|--|--|--|--|--|--|--|
| GROUP                             | GROUP LIGHT INTENSITY (µcd) |        |  |  |  |  |  |  |  |
| STANDARD                          | MIN.                        | MAX.   |  |  |  |  |  |  |  |
| E                                 | 180                         | 360    |  |  |  |  |  |  |  |
| F                                 | 280                         | 560    |  |  |  |  |  |  |  |
| G                                 | 450                         | 900    |  |  |  |  |  |  |  |
| Н                                 | 700                         | 1400   |  |  |  |  |  |  |  |
| I                                 | 1100                        | 2200   |  |  |  |  |  |  |  |
| К                                 | 1800                        | 3600   |  |  |  |  |  |  |  |
| L                                 | 2800                        | 5600   |  |  |  |  |  |  |  |
| М                                 | 4500                        | 9000   |  |  |  |  |  |  |  |
| Ν                                 | 7000                        | 14 000 |  |  |  |  |  |  |  |

<sup>•</sup> The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped in one tube (there will be no mixing of two groups in one tube).

In order to ensure availability, single brightness groups will not be orderable.

| COLOR CLASSIFICATION |       |       |      |      |       |      |  |  |  |
|----------------------|-------|-------|------|------|-------|------|--|--|--|
| GROUP                | ORANO | E RED | YEL  | LOW  | GREEN |      |  |  |  |
| GROOP                | MIN.  | MAX.  | MIN. | MAX. | MIN.  | MAX. |  |  |  |
| 1                    | 612   | 617   | 581  | 584  |       |      |  |  |  |
| 2                    | 616   | 621   | 583  | 586  |       |      |  |  |  |
| 3                    | 620   | 625   | 585  | 588  | 562   | 565  |  |  |  |
| 4                    |       |       | 587  | 590  | 564   | 567  |  |  |  |
| 5                    |       |       | 589  | 592  | 566   | 569  |  |  |  |
| 6                    |       |       | 591  | 594  | 568   | 571  |  |  |  |
| 7                    |       |       |      |      | 570   | 573  |  |  |  |
| 8                    |       |       |      |      | 572   | 575  |  |  |  |

Note

• Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm.

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## **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

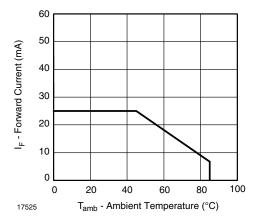


Fig. 1 - Forward Current vs. Ambient Temperature

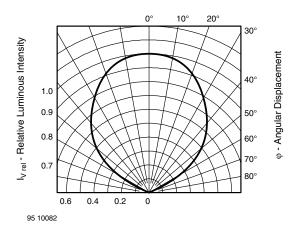


Fig. 2 - Relative Luminous Intensity vs. Angular Displacement

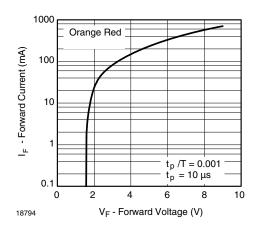


Fig. 3 - Forward Current vs. Forward Voltage

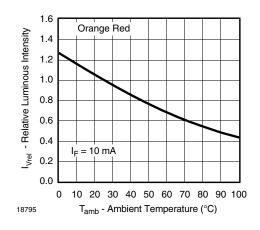


Fig. 4 - Relative Luminous Intensity vs. Ambient Temperature

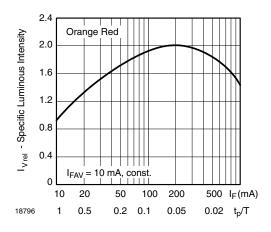


Fig. 5 - Relative Luminous Intensity vs. Forward Current/Duty Cycle

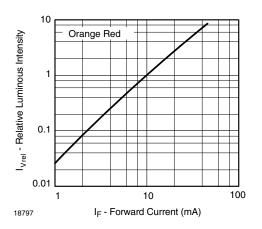


Fig. 6 - Relative Luminous Intensity vs. Forward Current

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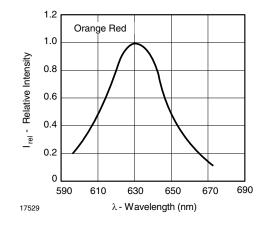


Fig. 7 - Relative Intensity vs. Wavelength

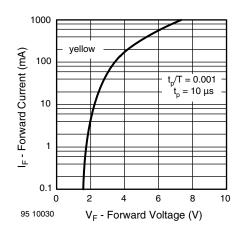


Fig. 8 - Forward Current vs. Forward Voltage

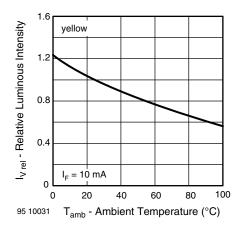
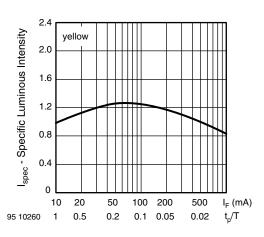


Fig. 9 - Relative Luminous Intensity vs. Ambient Temperature



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Fig. 10 - Relative Luminous Intensity vs. Forward Current/Duty Cycle

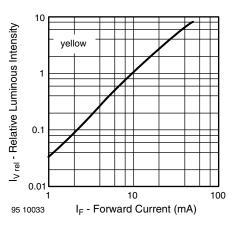


Fig. 11 - Relative Luminous Intensity vs. Forward Current

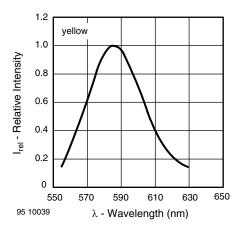
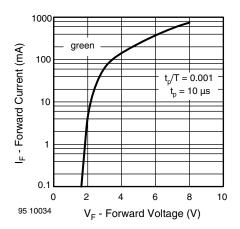


Fig. 12 - Relative Intensity vs. Wavelength

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Fig. 13 - Forward Current vs. Forward Voltage

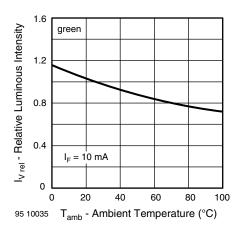


Fig. 14 - Relative Luminous Intensity vs. Ambient Temperature

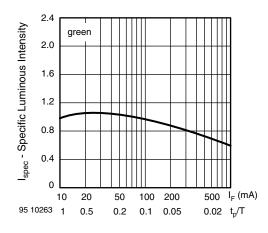


Fig. 15 - Specific Luminous Intensity vs. Forward Current

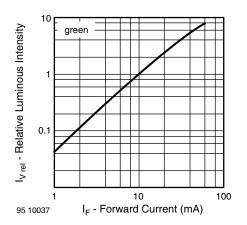


Fig. 16 - Relative Luminous Intensity vs. Forward Current

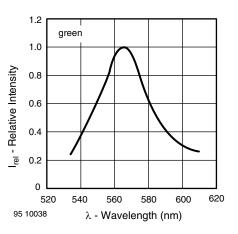


Fig. 17 - Relative Intensity vs. Wavelength

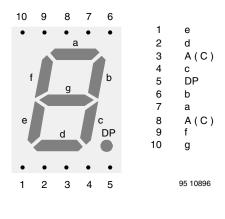


Fig. 18 - TDS.51..

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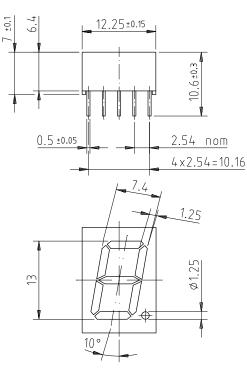
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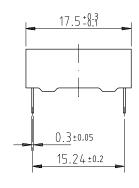


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## PACKAGE DIMENSIONS FOR TDS.51.. in millimeters







Drawing-No.: 6.544-5150.01-4 Issue: 1; 21.11.95 95 11344

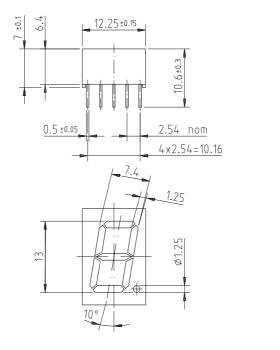
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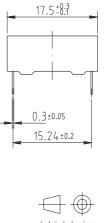


Display-13 mm Vishay Semiconductors

# Display-13 mm

## Package Dimensions in mm





technical drawings according to DIN specifications

# Display-13 mm

## **Vishay Semiconductors**



## **Ozone Depleting Substances Policy Statement**

## It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

### We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

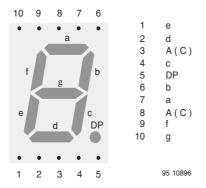
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# **Pin Connections 13 mm**

**Vishay Semiconductors** 

## Pin Connections 13 mm



## **Vishay Semiconductors**



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